

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant: Schloesser, et al.

Docket No.: INF-135

FAX RECEIVED

Serial No.: 10/777,128

Art Unit: 2818

APR 07 2006

Filed: February 13, 2004

Examiner: Andy Huynh

OFFICE OF PETITIONS

For: Architecture for Vertical Transistor Cells and Transistor-Controlled Memory Cells

Mail Stop DAC
Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450**PETITION FOR WITHDRAWAL FROM ISSUE UNDER 37 C.F.R. § 1.313(c)(2)**

PETITION

1. Applicants hereby petition for the withdrawal of this application from issue.

PATENT ISSUE FEE

2. The issue fee for this case was paid on January 16, 2006.

REASON(S) FOR WITHDRAWAL REQUEST

3. The reason for withdrawal from issue of this application is for consideration of an Information Disclosure Statement and Request for Continued Examination. 37 C.F.R. § 1.313(c)(2).

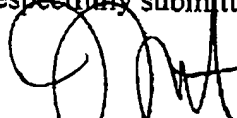
PETITION FEE

4. Petition Fees (37 C.F.R. § 1.17(h) (\$130.00)). The petition fee set forth in § 1.17(h), required by 35 C.F.R. § 1.313(a) is hereby authorized to be charged to Deposit Account No. 50-1065. Charge any additional fees required by this paper or credit any overpayment in the manner authorized above.

04/11/2006 CKHLOK 00000003 501065 10777128

01 FC:1464 130.00 DA

Respectfully submitted,



Ira S. Matsil
Reg. No. 35,272Slater & Matsil, L.L.P.
17950 Preston Rd., Suite 1000
Dallas, TX 75252
Tel: 972-732-1001
Fax: 972-732-9218



17950 Preston Road | Suite 1000 | Dallas, TX 75252

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OFFICE OF PETITIONS

(972) 732-1001

(972) 732-9218 FAX

www.slater-matsil.com

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TO: Commissioner for Patents
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FROM: Ira S. Matsil

DATE: April 7, 2006

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Certificate of Transmission under 37 C.F.R. § 1.8

I hereby certify that the following correspondence is being facsimile transmitted to the Patent and Trademark Office on April 7, 2006.

Facsimile Cover Sheet with Certificate of Transmission (1 page)
Petition for Withdrawal from Issue Under 37 C.F.R. § 1.313(c)(2) (1 original and 1 copy)
Request for Continued Examination (RCE) Transmittal (2 duplicate pages)
Information Disclosure Statement (1 page)
Form PTO/SB08A (1 page), with 4 references cited
Copy of one (1) cited reference (11 pages)

Signature

AnneMarie James
Name of Person Signing the Certificate